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APPLICATION DATA SHEET UNDER 37 C.F.R. §1.76

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**Inventor Information**

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**Application Information**

**Title:** METHOD OF EPITAXY ON A SILICON SUBSTRATE  
COMPRISING AREAS HEAVILY DOPED WITH ARSENIC

Total Drawing Sheets: 4

Formal Drawings? Yes

Application Type: Non-Provisional Utility

Art Unit: Unknown

Docket Number: S1022/8562

**Representative Information**

**Representative Customer Number::** 23628

**Continuity Information**

This application is a: Non-provisional

Claiming priority to: Non-Provisional application docket nos. S1022/8562 and S1022/8072

Serial Number: Not yet assigned

Filing Date: July 10, 2001

Status: Pending

**Prior Foreign Applications**

Foreign Application Number: 97/10032

Filing Date: July 31, 1997

Country: France

Priority Claimed: Yes

**Assignee Information (when available)**

Name of Assignee: STMicroelectronics S.A.

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